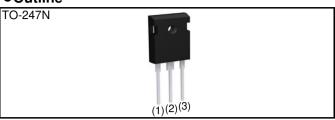


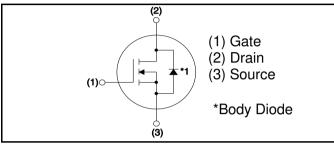
# SCT3030KL N-channel SiC power MOSFET

V <sub>DSS</sub>	1200V
R <sub>DS(on)</sub> (Typ.)	30mΩ
$I_{D}^{*1}$	72A
P <sub>D</sub>	339W

## Outline



## Inner circuit



## 2) Fast switching speed

Features

3) Fast reverse recovery

1) Low on-resistance

- 4) Easy to parallel
- 5) Simple to drive
- 6) Pb-free lead plating ; RoHS compliant

### Application

- $\cdot$  Solar inverters
- DC/DC converters
- Switch mode power supplies
- Induction heating
- Motor drives

### Packaging specifications

	Packing	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	30
	Taping code	C11
	Marking	SCT3030KL

## ●Absolute maximum ratings (T<sub>vj</sub> = 25°C unless otherwise specified)

,				
Parameter		Symbol	Value	Unit
Drain - Source Voltage		V <sub>DSS</sub>	1200	V
Continuous Drain current		ا <sub>D</sub> *1	72	А
Continuous Drain current	$T_c = 100^{\circ}C$	ا <sub>D</sub> *1	51	А
Pulsed Drain current ( $T_c = 25^{\circ}C$ )		I <sub>D,pulse</sub> *2	180	А
Gate - Source voltage (DC)		V <sub>GSS</sub>	-4 to +22	V
Gate - Source surge voltage (t <sub>surge</sub> < 300nsec)		V <sub>GSS_surge</sub> *3	-4 to +26	V
Recommended drive voltage		V <sub>GS_op</sub> <sup>*4</sup>	0 / +18	V
Virtual Junction temperature		T <sub>vj</sub>	175	°C
Range of storage temperature		T <sub>stg</sub>	-55 to +175	°C

## •Electrical characteristics ( $T_{vj}$ = 25°C unless otherwise specified)

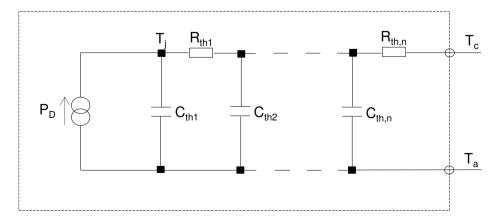
Doromotor	Symbol	Conditions	Values			Unit
Parameter	Symbol Conditions –		Min.	Тур.	Max.	Unit
		$V_{GS} = 0V, I_D = 1mA$				
Drain - Source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$T_{vj} = 25^{\circ}C$	1200	-	-	V
		T <sub>vj</sub> = -55°C	1200	-	-	
		$V_{GS} = 0V, V_{DS} = 1200V$				
Zero Gate voltage Drain current	I <sub>DSS</sub>	$T_{vj} = 25^{\circ}C$	-	1	10	μA
		T <sub>vj</sub> = 150°C	-	2	-	
Gate - Source leakage current	I <sub>GSS+</sub>	$V_{GS} = +22V$ , $V_{DS} = 0V$	-	-	100	nA
Gate - Source leakage current	I <sub>GSS-</sub>	$V_{GS} = -4V$ , $V_{DS} = 0V$	-	-	-100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10V, I_{D} = 13.3mA$	2.7	-	5.6	V
		$V_{GS} = 18V, I_{D} = 27A$				
Static Drain - Source on - state resistance	${\sf R}_{\sf DS(on)}$ *5	$T_{vj} = 25^{\circ}C$	-	30	39	mΩ
		T <sub>vj</sub> = 150°C	-	51	-	
Gate input resistance	R <sub>G</sub>	f = 1MHz, open drain	-	5	-	Ω

#### Thermal resistance

Parameter	Symbol	Values			Unit
Faranteler	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	R <sub>thJC</sub>	-	0.34	0.44	K/W

#### •Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R <sub>th1</sub>	4.83E-03		C <sub>th1</sub>	1.40E-03	
R <sub>th2</sub>	1.73E-01	K/W	C <sub>th2</sub>	1.13E-02	Ws/K
R <sub>th3</sub>	1.63E-01		C <sub>th3</sub>	6.02E-02	





## •Electrical characteristics ( $T_{vj} = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Conditions		Values		Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Transconductance	g <sub>fs</sub> *5	$V_{DS} = 10V, I_{D} = 27A$	-	10.8	-	S
Input capacitance	C <sub>iss</sub>	$V_{GS} = 0V$	-	2222	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 800V	-	180	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	72	-	
Effective output capacitance, energy related	C <sub>o(er)</sub>	$V_{GS} = 0V$ $V_{DS} = 0V$ to 600V	-	157	-	pF
Total Gate charge	$Q_g^{*5}$	$V_{DS} = 600V$ $I_{D} = 27A$	-	131	-	
Gate - Source charge	Q <sub>gs</sub> *5	$V_{GS} = 18V$	-	22	-	nC
Gate - Drain charge	$Q_{gd}$ *5	See Fig. 1-1.	-	69	-	
Turn - on delay time	t <sub>d(on)</sub> *5	V <sub>DS</sub> = 400V I <sub>D</sub> = 18A	-	24	-	
Rise time	t <sub>r</sub> *5	V <sub>GS</sub> = 0V/+18V	-	42	-	20
Turn - off delay time	t <sub>d(off)</sub> *5	$R_{G} = 0\Omega$ $R_{L} = 22\Omega$	-	61	-	ns
Fall time	t <sub>f</sub> *5	See Fig. 1-1, 1-2.	-	29	-	
Turn - on switching loss	E <sub>on</sub> *5	$V_{DS} = 600V$ $V_{GS}=0V/18V, I_{D} = 27A$ $R_{G} = 0\Omega, L = 250\mu H$	-	468	-	
Turn - off switching loss	E <sub>off</sub> *5	$E_{on}$ includes diode reverse recovery $L_{\sigma} = 50$ nH, $C_{\sigma} = 200$ pF See Fig. 2-1, 2-2.	-	204	-	μJ



### SCT3030KL

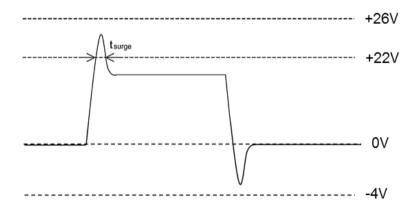
## ●Body diode electrical characteristics (Source-Drain) (T<sub>vj</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Conditions		Values		Unit
Farameler	Зушоо	Conditions	Min.	Тур.	Max.	Unit
Body diode continuous, forward current	ا <sub>S</sub> *1	T <sub>c</sub> = 25°C	-	-	72	А
Body diode direct current, pulsed	I <sub>SM</sub> *2	T <sub>c</sub> = 25 0	-	-	180	А
Forward voltage	$V_{SD}$ *5	$V_{GS} = 0V, I_S = 27A$	-	3.2	-	V
Reverse recovery time	t <sub>rr</sub> *5	$I_F = 27A$ $V_B = 600V$	-	27	-	ns
Reverse recovery charge	Q <sub>rr</sub> *5	di/dt = 1100A/µs	-	135	-	nC
Peak reverse recovery current	I I <sub>rrm</sub> *5	$L_{\sigma} = 50$ nH, $C_{\sigma} = 200$ pF See Fig. 3-1, 3-2.	-	10	_	А

\*1 Limited by maximum  $T_{vj}$  and for Max.  $R_{thJC}$ .

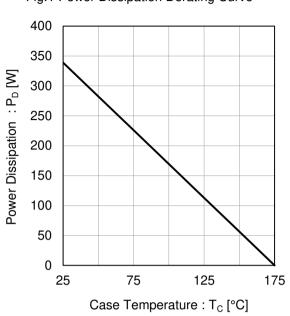
\*2 PW  $\leq$  10µs, Duty cycle  $\leq$  1%

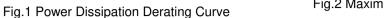
\*3 Example of acceptable  $V_{\text{GS}}$  waveform



- \*4 Please be advised not to use SiC-MOSFETs with V<sub>GS</sub> below 13V as doing so may cause thermal runaway.
- \*5 Pulsed







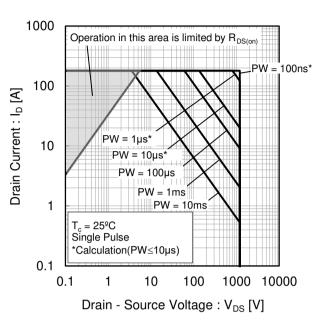
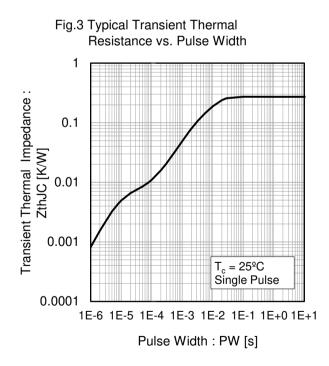
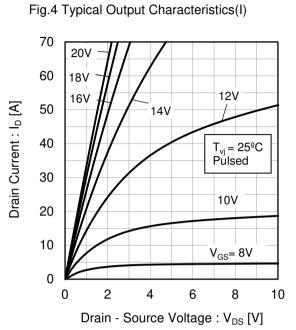


Fig.2 Maximum Safe Operating Area









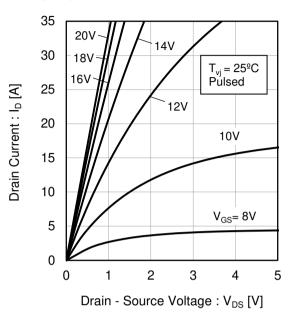
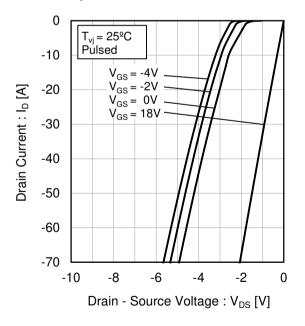
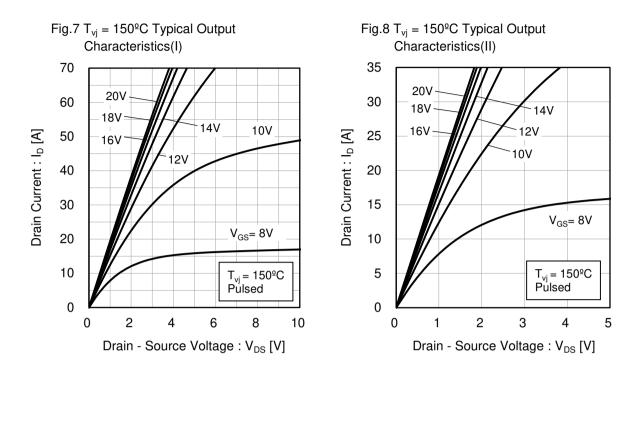
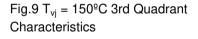


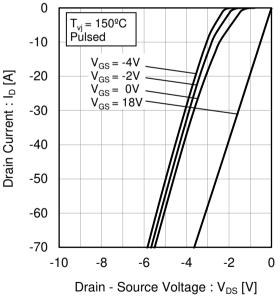
Fig.6 T<sub>vi</sub> = 25°C 3rd Quadrant Characteristics

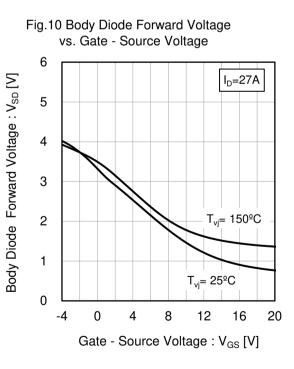




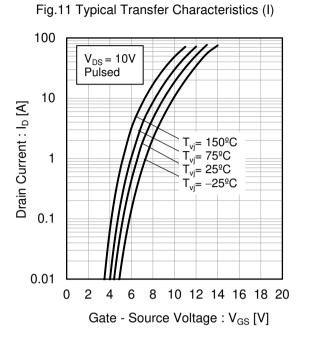










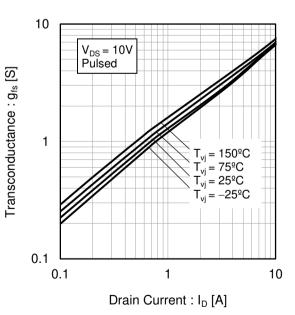


70 V<sub>DS</sub> = 10V Pulsed 60 Drain Current : I<sub>D</sub> [A] 50 40 T<sub>vj</sub>= 150ºC  $T_{vj}^{v_j} = 75^{\circ}C$ 30 T<sub>vj</sub>= 25⁰C T<sub>vj</sub>= −25ºC 20 10 0 6 8 10 12 14 16 18 20 2 4 0 Gate - Source Voltage : V<sub>GS</sub> [V]

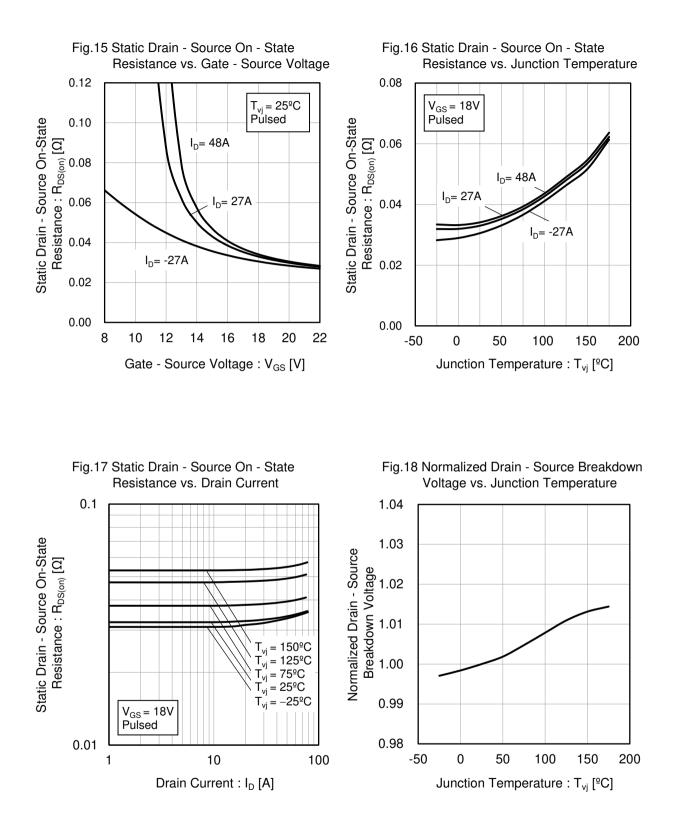
Fig.12 Typical Transfer Characteristics (II)

Fig.13 Gate Threshold Voltage vs. Junction Temperature 6 Gate Threshold Voltage : V GS(th) [V]  $V_{DS} = 10V$  $I_{D} = 13.3$ mA 5 4 3 2 1 0 -50 0 50 100 200 150 Junction Temperature : T<sub>vj</sub> [ºC]

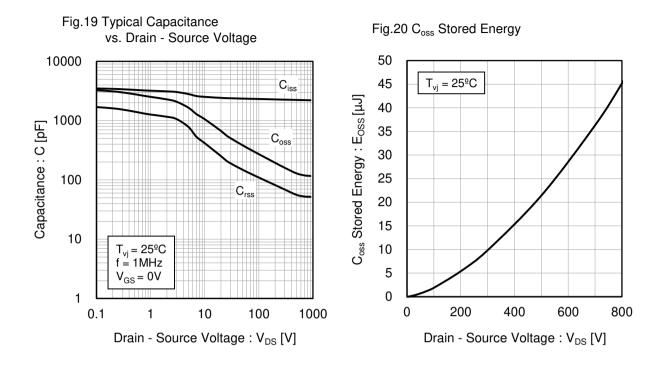
Fig.14 Transconductance vs. Drain Current



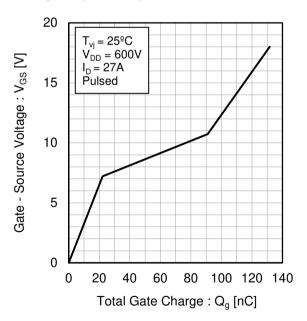


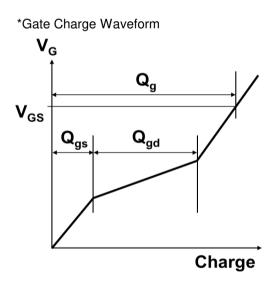




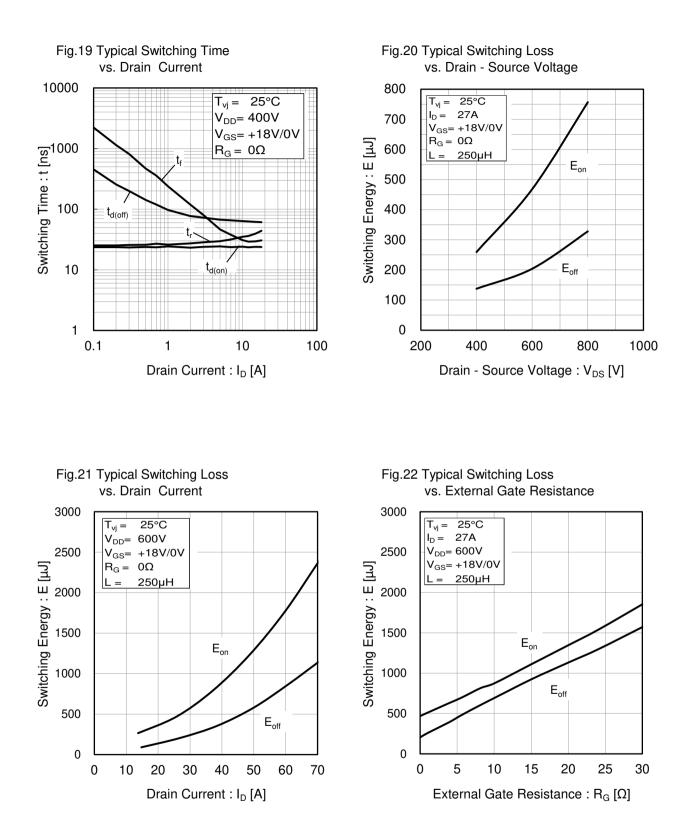


#### Fig.21 Dynamic Input Characteristics





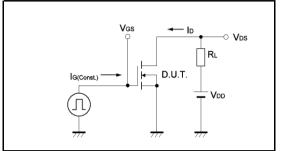




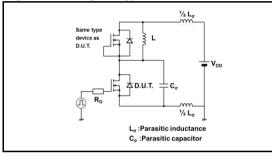


### Measurement circuits and waveforms

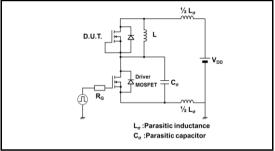
Fig.1-1 Gate Charge and Switching Time Measurement Circuit



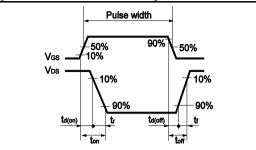
#### Fig.2-1 Switching Energy Measurement Circuit



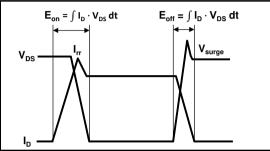
#### Fig.3-1 Reverse Recovery Time Measurement Circuit



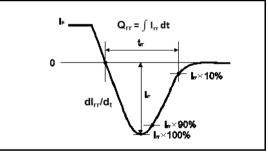
#### Fig.1-2 Waveforms for Switching Time



#### Fig.2-2 Waveforms for Switching Energy Loss

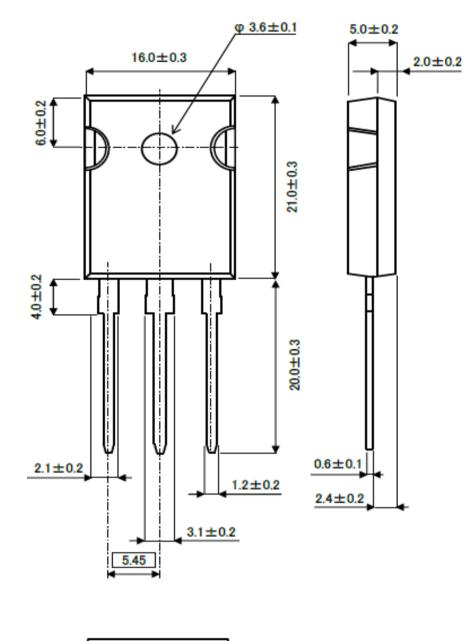


#### Fig.3-2 Reverse Recovery Waveform





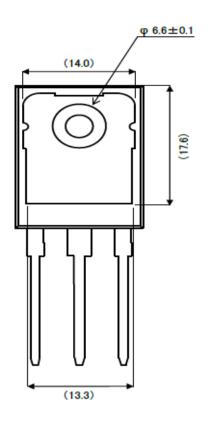
#### Package Dimensions





Unit: mm



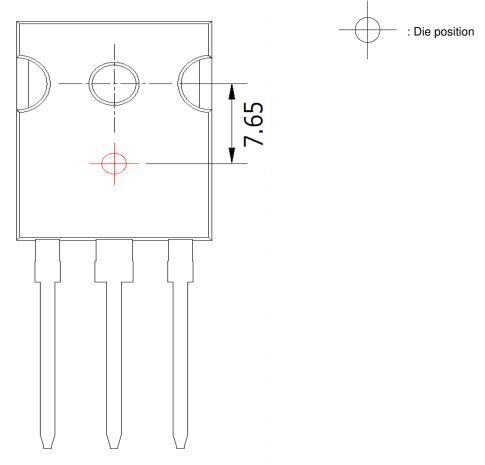


Unit: mm





### Die Bonding Layout



•Front view of the packaging.

•Dimensions are design values.

·If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm





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